



# NCE N-Channel Enhancement Mode Power MOSFET

#### Description

The NCE8580D uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

#### **General Features**

- $V_{DS} = 85V, I_D = 80A$  $R_{DS(ON)} < 8.5m\Omega @ V_{GS} = 10V$  (Typ:6.8m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for convertors and power controls
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

## Application

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply

#### 100% UIS TESTED!

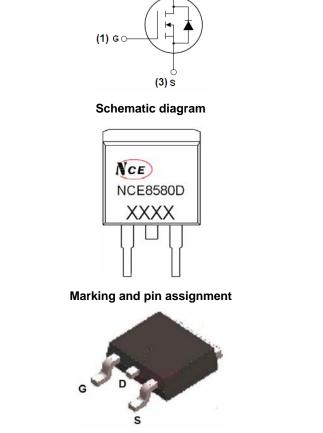
#### **100% ΔVds TESTED!**

## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE8580D	NCE8580D	TO-263-2L	-	-	-

#### Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	85	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	80	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	60	A
Pulsed Drain Current	I <sub>DM</sub>	320	A
Maximum Power Dissipation	PD	170	W
Peak diode recovery voltage	dv/dt	15	V/ns
Derating factor		1.13	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	620	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C



(2) D

TO-263-2L top view





NCE8580D

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{\theta JC}$	0.88	°C <b>/W</b>

## Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	87	89	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =85V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2	2.85	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	6.8	8.5	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =25V,I <sub>D</sub> =40A	110	-	-	S
Dynamic Characteristics (Note4)			•			•
Input Capacitance	C <sub>lss</sub>		-	4400	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,	-	340	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	260	-	PF
Switching Characteristics (Note 4)			•			•
Turn-on Delay Time	t <sub>d(on)</sub>		-	18	-	nS
Turn-on Rise Time	tr	VDD=30V,ID=2A,RL=15Ω	-	12	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	,RG=2.5Ω,VGS=10V	-	56	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	N/ 00\// 00A	-	100	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =30V,I <sub>D</sub> =30A,	-	20	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	30	-	nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	80	А
Reverse Recovery Time	t <sub>rr</sub>	Tj=25℃,I <sub>F</sub> =75A	-		36	nS
Reverse Recovery Charge	Qrr	di/dt=100A/µs <sup>(Note3)</sup>	-		56	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=40V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

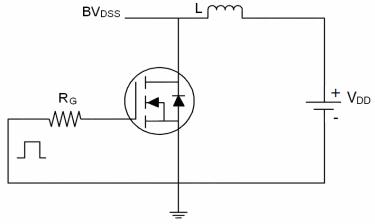


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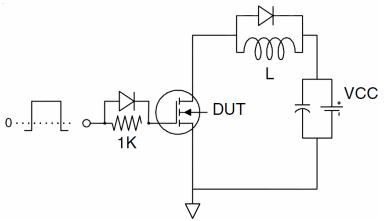


# **Test Circuit**

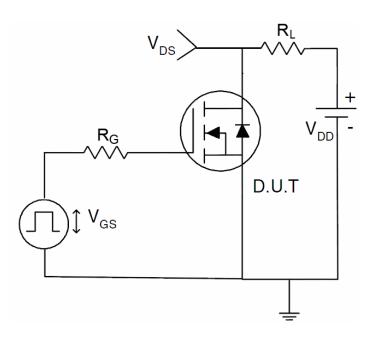
1) E<sub>AS</sub> Test Circuits



## 2) Gate Charge Test Circuit



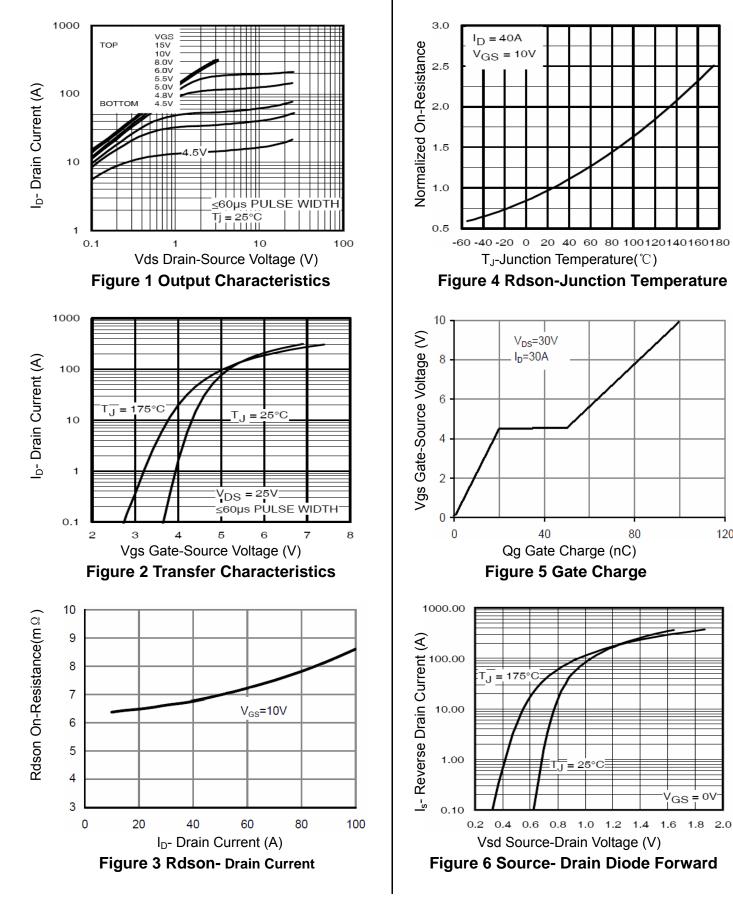
## 3) Switch Time Test Circuit







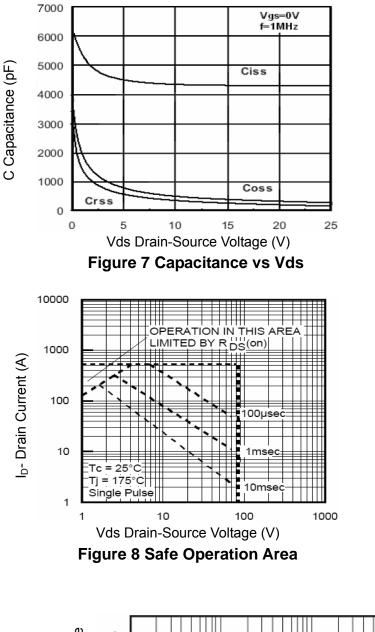
## **Typical Electrical and Thermal Characteristics (Curves)**



120







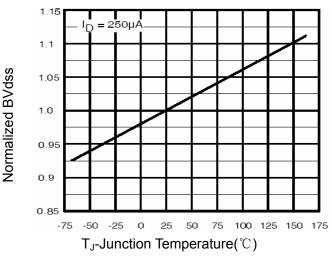


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

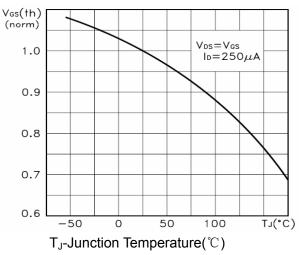
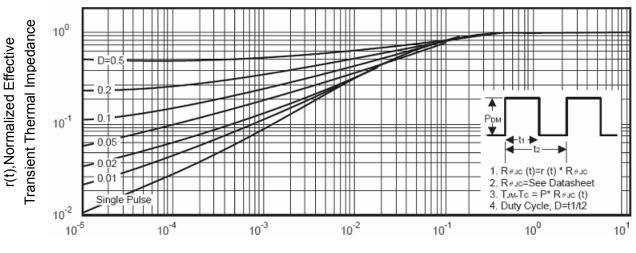
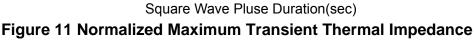


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



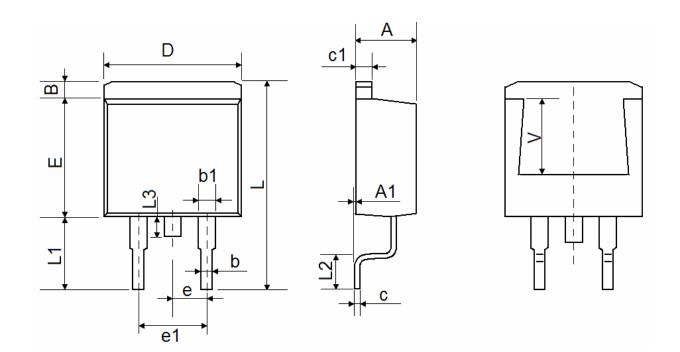




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# TO-263-2L Package Information



Cumhal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.470	4.670	0.176	0.184	
A1	0.000	0.150	0.000	0.006	
В	1.170	1.370	0.046	0.054	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
E	8.500	8.900	0.335	0.350	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
L	15.050	15.450	0.593	0.608	
L1	5.080	5.480	0.200	0.216	
L2	2.340	2.740	0.092	0.108	
L3	1.300	1.700	0.051	0.067	
V	5.600 REF			REF	





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